Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
11.230 inches	
End Application:	
Sonar dome rubber windows (sdrws); an/sqq-89 surface ship asw combat system; ticonderoga class cg (47); sp	vruance class dd (963)
Mounting Facility Quantity:	
1	
Joint Electronic Device Engineering Council/jedec/case Outline Designation:	
T0-118	
Electrode Internally-electrically Connected To Case:	
Base	
Mounting Method:	
Threaded stud	
Overall Width Across Flats:	
1.690 inches	
Thread Size:	
0.750 inches	
Criticality Code Justification:	
Feat	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
1.7 forward voltage, peak and 3.5 gate trigger voltage, dc and 400.0 reverse voltage, peak	
Current Rating Per Characteristic:	
300.00 amperes forward current, total rms megahertz and 6000.00 amperes source cutoff current peak	
Maximum Operating Tempurature Per Measurement Point:	
125.0 degrees celsius case	
Special Features:	
Weapon system essential	
Thread Series Designator:	
Unf	
Terminal Type And Quantity:	
3 tab, solder lug and 1 threaded stud	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	